

Amendments to the Specification:

Please replace the paragraph beginning at page 6, line 1 with the following rewritten paragraph:

In all the embodiments, an electron transport layer 12 may be located between cathode 6 and light-emitting layer-4₅ or between cathode 6 and second hole blocking layer 7. The material of such an electron transport layer is characterized by a high electron affinity. Suitable materials are, for example, tris-(8-hydroxyquinolato)aluminum (Alq_3) or electron-poor heterocycles such as 1,3,4-oxadiazoles or 1,2,4-triazoles. FIG. 4 shows a light-emitting device which has an electron transport layer 12 between the cathode 6 and the second hole blocking layer 7.